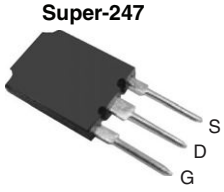
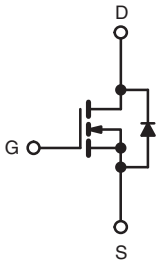
Power MOSFET

PRODUCT SUMMARY		
V_{DS} (V)	500	
$R_{DS(on)}$ (Ω)	V_{GS} = 10 V	0.078
Q_g (Max.) (nC)	350	
Q_{gs} (nC)	85	
Q_{gd} (nC)	180	
Configuration	Single	

Super-247





N-Channel MOSFET

FEATURES

- Low Gate Charge Q_g Results in Simple Drive Requirement
- Improved Gate, Avalanche and Dynamic dV/dt Ruggedness
- Fully Characterized Capacitance and Avalanche Voltage and Current
- Low $R_{DS(on)}$
- Compliant to RoHS Directive 2002/95/EC

Available

RoHS* COMPLIANT

APPLICATIONS

- Switch Mode Power Supply (SMPS)
- Uninterruptible Power Supply
- High Speed Power Switching
- Hard Switched and High Frequency Circuits

ORDERING INFORMATION	
Package	Super-247
Lead (Pb)-free	IRFPS43N50KPbF
	SiHFPS43N50K-E3
SnPb	IRFPS43N50K
	SiHFPS43N50K

ABSOLUTE MAXIMUM RATINGS (T_C = 25 °C, unless otherwise noted)

PARAMETER			SYMBOL	LIMIT	UNIT
Drain-Source Voltage			V_{DS}	500	V
Gate-Source Voltage			V_{GS}	± 30	
Continuous Drain Current	V_{GS} at 10 V	T_C = 25 °C	I_D	47	A
		T_C = 100 °C		29	
Pulsed Drain Current[a]			I_{DM}	190	
Linear Derating Factor				4.3	W/°C
Single Pulse Avalanche Energy[b]			E_{AS}	910	mJ
Repetitive Avalanche Current[a]			I_{AR}	47	A
Repetitive Avalanche Energy[a]			E_{AR}	54	mJ
Maximum Power Dissipation	T_C = 25 °C		P_D	540	W
Peak Diode Recovery dV/dt[c]			dV/dt	9.0	V/ns
Operating Junction and Storage Temperature Range			T_J, T_{stg}	- 55 to + 150	°C
Soldering Recommendations (Peak Temperature)	for 10 s			300[d]	

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).

b. Starting T_J = 25 °C, L = 0.82 mH, R_g = 25 Ω, I_{AS} = 47 A (see fig. 12c).

c. $I_{SD} \leq 47$ A, dI/dt ≤ 230 A/μs, $V_{DD} \leq V_{DS}$, $T_J \leq 150$ °C.

d. 1.6 mm from case.

* Pb containing terminations are not RoHS compliant, exemptions may apply

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THERMAL RESISTANCE RATINGS				
PARAMETER	**SYMBOL**	**TYP.**	**MAX.**	**UNIT**
Maximum Junction-to-Ambient	R_{thJA}	-	40	°C/W
Case-to-Sink, Flat, Greased Surface	R_{thCS}	0.24	-	
Maximum Junction-to-Case (Drain)	R_{thJC}	-	0.23	

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNIT**
Static							
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = 250 µA		500	-	-	V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	Reference to 25 °C, I_D = 1 mA		-	0.60	-	V/°C
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 250 µA		3.0	-	5.0	V
Gate-Source Leakage	I_{GSS}	V_{GS} = ± 30 V		-	-	± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = 500 V, V_{GS} = 0 V		-	-	50	µA
		V_{DS} = 400 V, V_{GS} = 0 V, T_J = 125 °C		-	-	250	
Drain-Source On-State Resistance	$R_{DS(on)}$	V_{GS} = 10 V	I_D = 28 A[b]	-	0.078	0.090	Ω
Forward Transconductance	g_{fs}	V_{DS} = 50 V, I_D = 28 A		23	-	-	S
Dynamic							
Input Capacitance	C_{iss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1.0 MHz, see fig. 5		-	8310	-	pF
Output Capacitance	C_{oss}			-	960	-	
Reverse Transfer Capacitance	C_{rss}			-	120	-	
Output Capacitance	C_{oss}	V_{GS} = 0 V	V_{DS} = 1.0 V, f = 1.0 MHz	-	10170	-	
			V_{DS} = 400 V, f = 1.0 MHz	-	240	-	
Effective Output Capacitance	C_{oss} eff.		V_{DS} = 0 V to 400 V[c]	-	440	-	
Total Gate Charge	Q_g	V_{GS} = 10 V	I_D = 47 A, V_{DS} = 400 V, see fig. 6 and 13[b]	-	-	350	nC
Gate-Source Charge	Q_{gs}			-	-	85	
Gate-Drain Charge	Q_{gd}			-	-	180	
Turn-On Delay Time	$t_{d(on)}$		V_{DD} = 250 V, I_D = 47 A, R_G = 1.0 Ω, see fig. 10[b]	-	25	-	ns
Rise Time	t_r			-	140	-	
Turn-Off Delay Time	$t_{d(off)}$			-	55	-	
Fall Time	t_f			-	74	-	
Drain-Source Body Diode Characteristics							
Continuous Source-Drain Diode Current	I_S	MOSFET symbol showing the integral reverse p - n junction diode 		-	-	47	A
Pulsed Diode Forward Current[a]	I_{SM}			-	-	190	
Body Diode Voltage	V_{SD}	T_J = 25 °C, I_S = 47 A, V_{GS} = 0 V[b]		-	-	1.5	V
Body Diode Reverse Recovery Time	t_{rr}	T_J = 25 °C, I_F = 47 A, dI/dt = 100 A/µs[b]		-	620	940	ns
Body Diode Reverse Recovery Charge	Q_{rr}			-	14	21	µC
Body Diode Recovery Current	I_{RRM}			-	38	-	A
Forward Turn-On Time	t_{on}	Intrinsic turn-on time is negligible (turn-on is dominated by L_S and L_D)					

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature (see fig. 11).

b. Pulse width ≤ 400 µs; duty cycle ≤ 2 %.

c. C_{oss} eff. is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DS}.

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

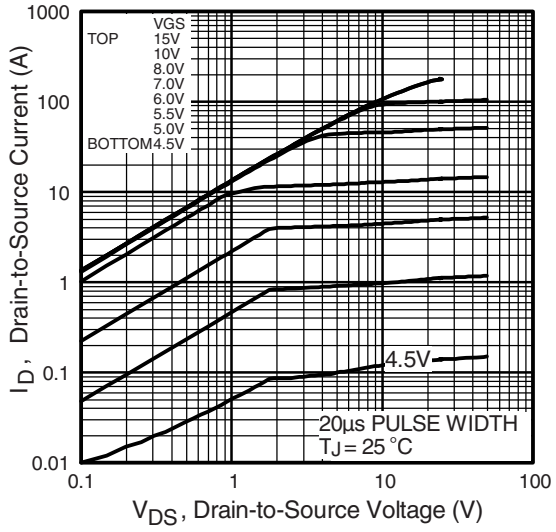

Fig. 1 - Typical Output Characteristics

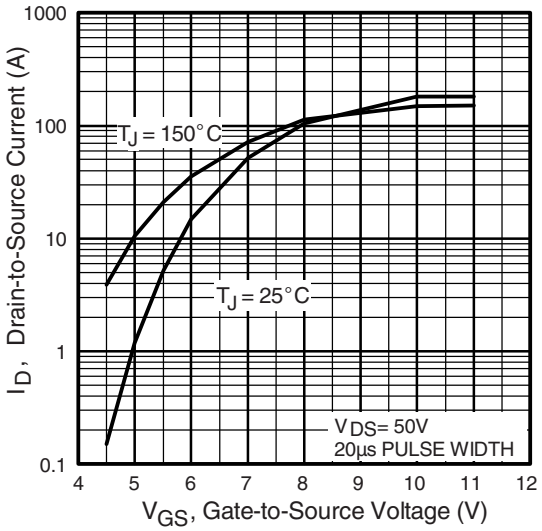

Fig. 3 - Typical Transfer Characteristics

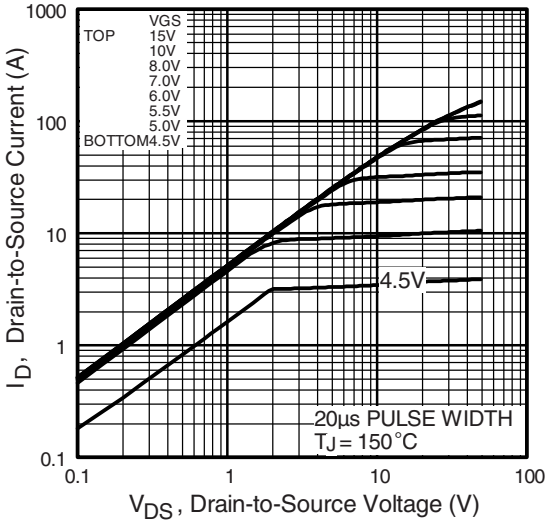

Fig. 2 - Typical Output Characteristics

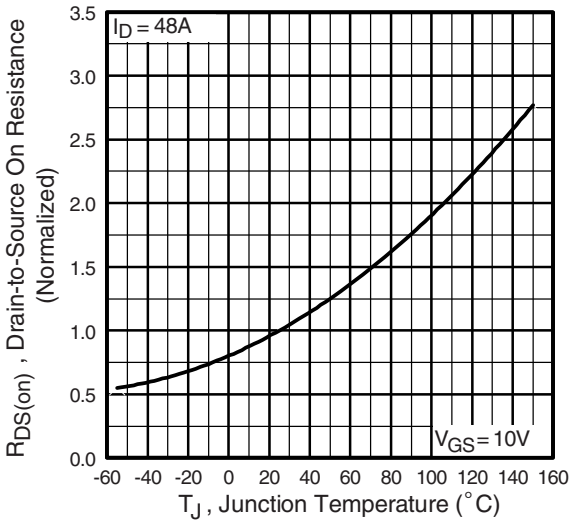

Fig. 4 - Normalized On-Resistance vs. Temperature

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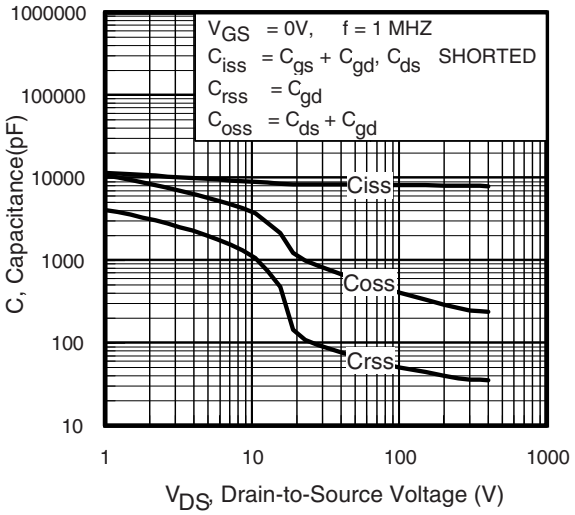

Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

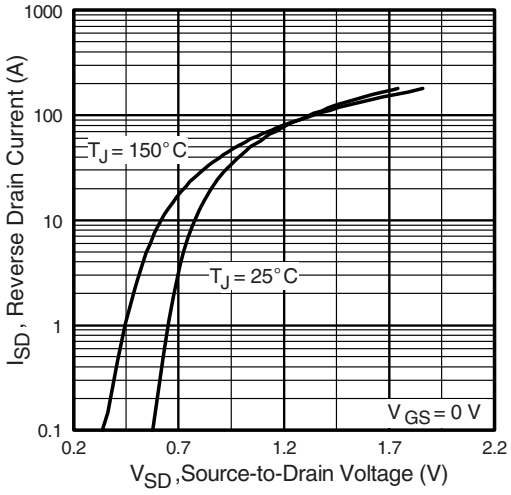

Fig. 7 - Typical Source-Drain Diode Forward Voltage

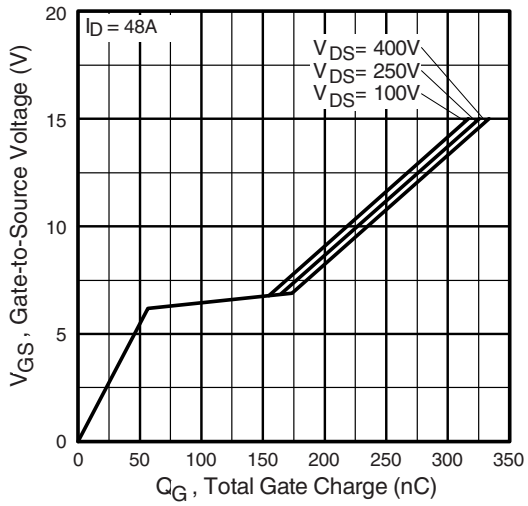

Fig. 6 - Typical Gate Charge vs. Gate-to-Source Voltage

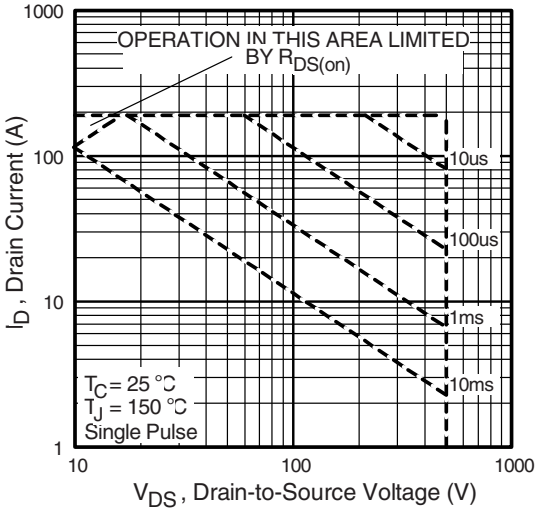

Fig. 8 - Maximum Safe Operating Area

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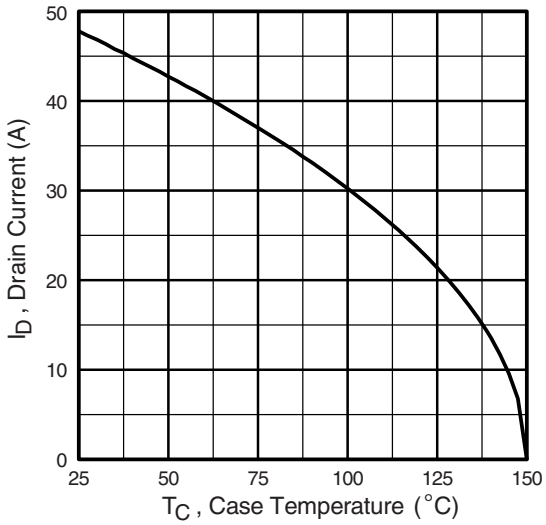

Fig. 9 - Maximum Drain Current vs. Case Temperature

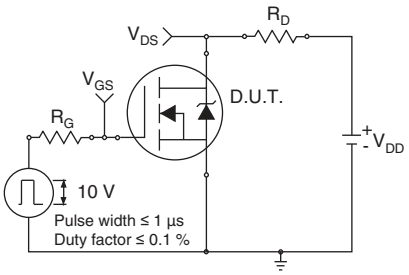

Fig. 10a - Switching Time Test Circuit

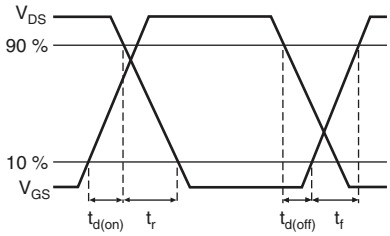

Fig. 10b - Switching Time Waveforms

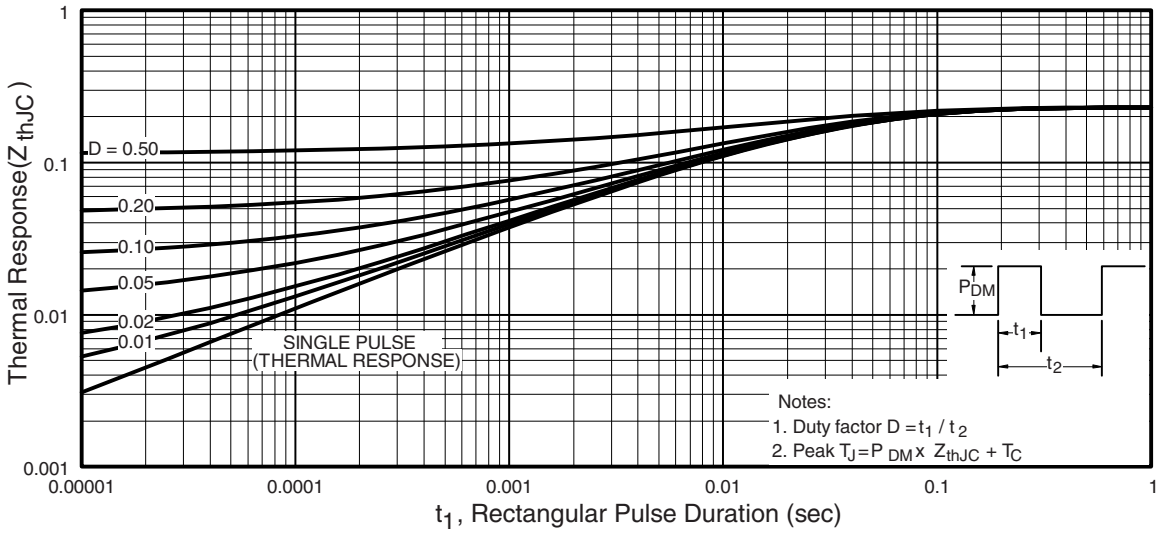

Fig. 11 - Maximum Effective Transient Thermal Impedance, Junction-to-Case

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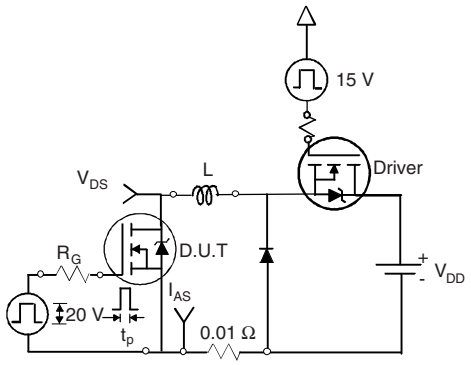

Fig. 12a - Unclamped Inductive Test Circuit

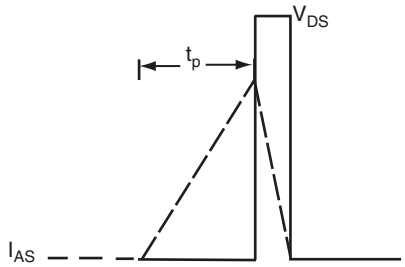

Fig. 12b - Unclamped Inductive Waveforms

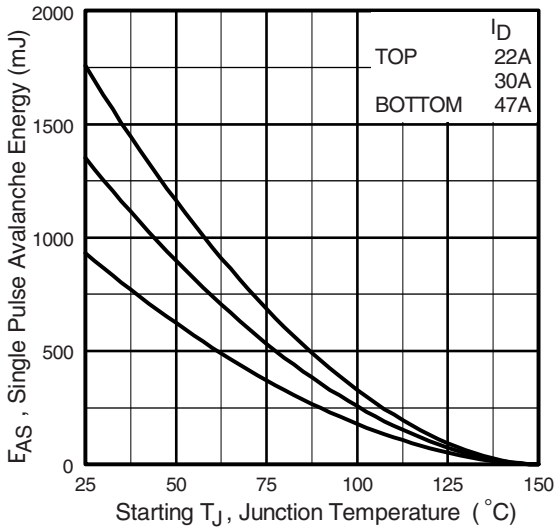

Fig. 12c - Maximum Avalanche Energy vs. Drain Current

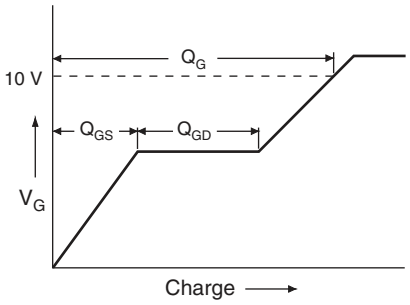

Fig. 13a - Basic Gate Charge Waveform

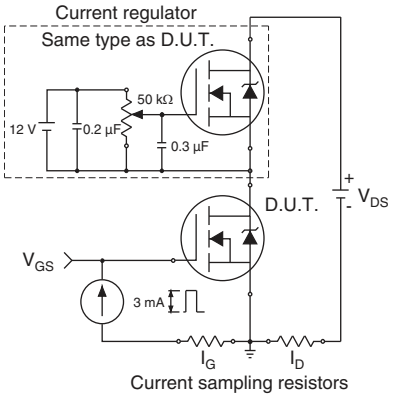

Fig. 13b - Gate Charge Test Circuit

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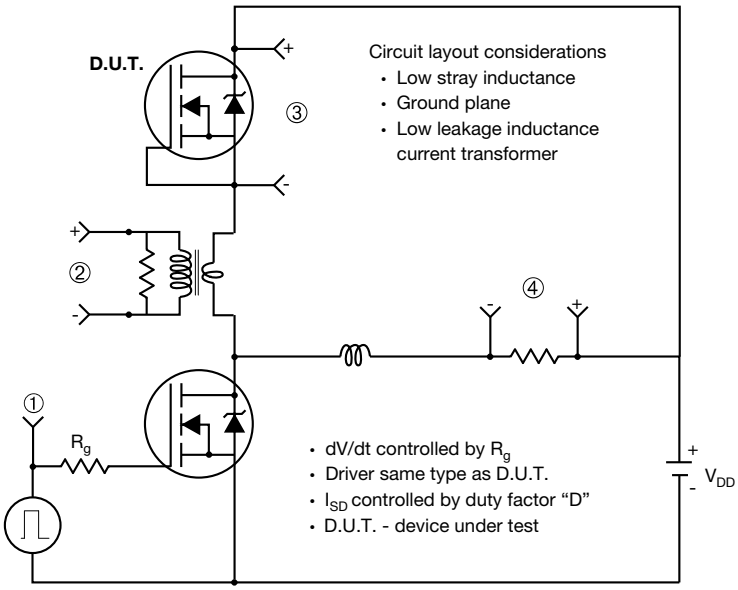
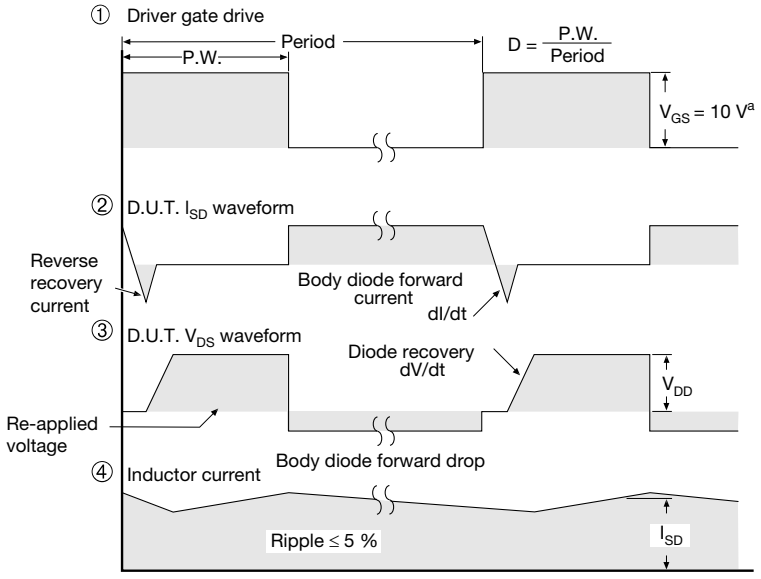
Peak Diode Recovery dV/dt Test Circuit





Note

a. V_{GS} = 5 V for logic level devices

Fig. 14 - For N-Channel

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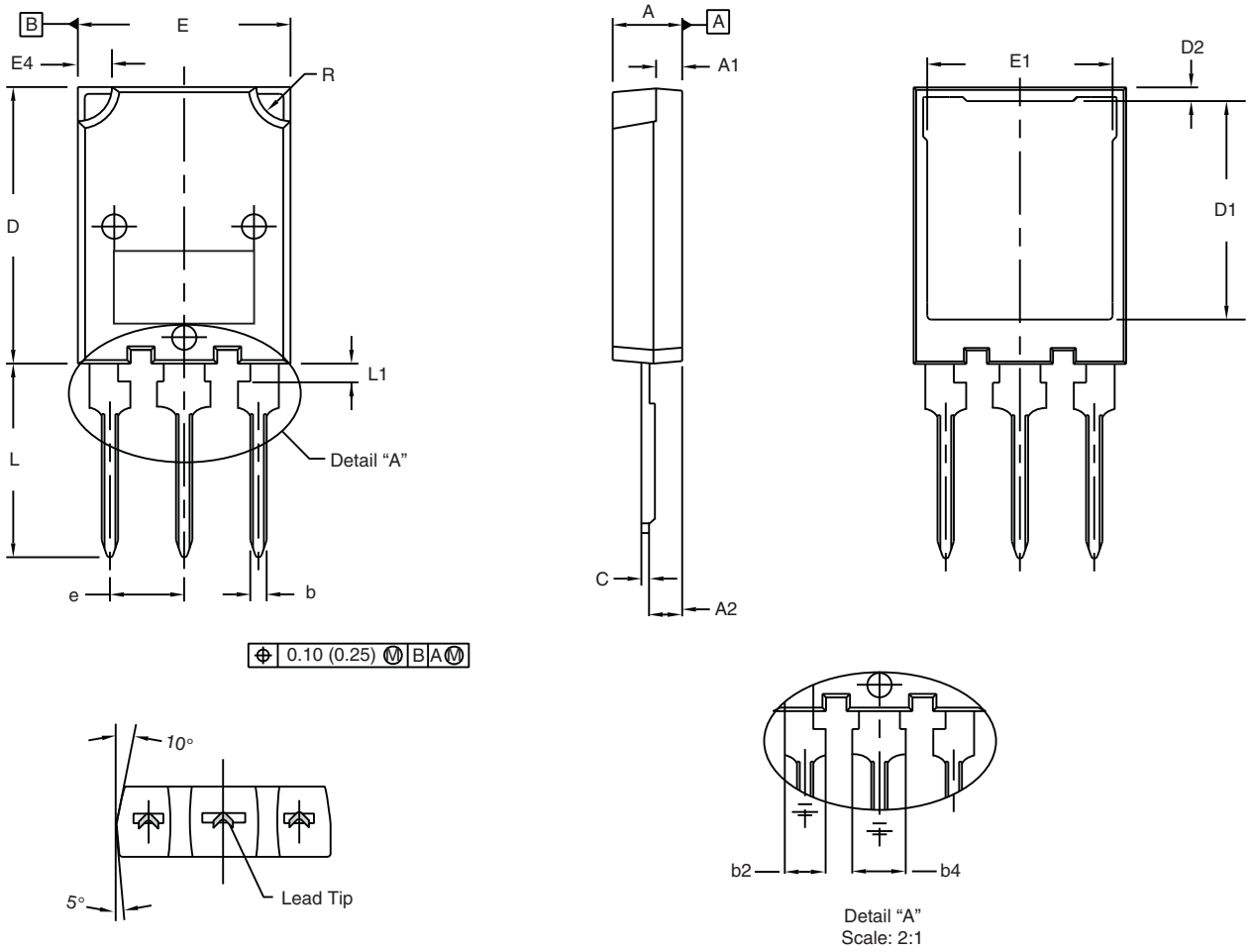
TO-274AA (High Voltage)



DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
A	4.70	5.30	0.185	0.209
A1	1.50	2.50	0.059	0.098
A2	2.25	2.65	0.089	0.104
b	1.30	1.60	0.051	0.063
b2	1.80	2.20	0.071	0.087
b4	3.00	3.25	0.118	0.128
c (1)	0.38	0.89	0.015	0.035
D	19.80	20.80	0.780	0.819

DIM.	MILLIMETERS		INCHES	
	MIN.	MAX.	MIN.	MAX.
D1	15.50	16.10	0.610	0.634
D2	0.70	1.30	0.028	0.051
E	15.10	16.10	0.594	0.634
E1	13.30	13.90	0.524	0.547
e	5.45 BSC		0.215 BSC	
L	13.70	14.70	0.539	0.579
L1	1.00	1.60	0.039	0.063
R	2.00	3.00	0.079	0.118

ECN: X17-0056-Rev. B, 27-Mar-17
DWG: 5975

Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outer extremes of the plastic body
- Outline conforms to JEDEC® outline to TO-274AA

(1) Dimension measured at tip of lead

For technical questions, contact: hvm@vishay.com

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